# SN74AHCT08Q-Q1 車載対応、クワッド、2 入力、正論理 AND ゲート

## 1 特長

- 車載アプリケーション認定済み
- EPIC™ (enhanced-performance implanted CMOS) プロセス
- 入力は TTL 電圧互換
- JESD 17 準拠で 250mA 超のラッチアップ性能

## 2 アプリケーション

- パワー・グッド信号の結合
- イネーブル信号の結合

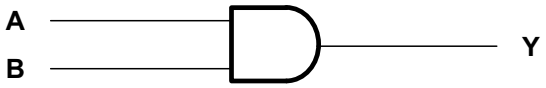
## 3 概要

SN74AHCT08Q-Q1 デバイスは、クワッド 2 入力正論理 AND ゲートです。これらのデバイスは、ブール関数 $Y = A \times B$ or $Y = \overline{\overline{A} + \overline{B}}$ を正論理で実行します。

**パッケージ情報**

| 部品番号 | パッケージ (1) | パッケージ サイズ(2) | 本体サイズ (3) |
|---|---|---|---|
| SN74AHCT08Q-Q1 | D (SOIC、14) | 8.65mm × 6mm | 8.65mm × 3.91mm |
| | PW (TSSOP、14) | 5.00mm × 6.4mm | 5.00mm × 4.40mm |
| | BQA (WQFN、14) | 3.00mm × 2.50mm | 3.00mm × 2.50mm |

(1) 詳細については、セクション 11 を参照してください。
(2) パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。
(3) 本体サイズ (長さ×幅) は公称値であり、ピンは含まれません。




**概略回路図**

このリソースの元の言語は英語です。翻訳は概要を便宜的に提供するもので、自動化ツール (機械翻訳) を使用していることがあり、TI では翻訳の正確性および妥当性につきましては一切保証いたしません。実際の設計などの前には、ti.com で必ず最新の英語版をご参照くださいますようお願いいたします。

# Table of Contents

**1 特長** ... 1
**2 アプリケーション** ... 1
**3 概要** ... 1
**4 Pin Configuration and Functions** ... 3
**5 Specifications** ... 4
5.1 Absolute Maximum Ratings ... 4
5.2 ESD Ratings ... 4
5.3 Recommended Operating Conditions ... 4
5.4 Thermal Information ... 5
5.5 Electrical Characteristics ... 5
5.6 Switching Characteristics, $V_{CC}$ = 5 V ± 0.5 V ... 5
5.7 Noise Characteristics ... 5
5.8 Operating Characteristics ... 6
5.9 Typical Characteristics ... 6
**6 Parameter Measurement Information** ... 7
**7 Detailed Description** ... 8
7.1 Overview ... 8
7.2 Functional Block Diagram ... 8
7.3 Feature Description ... 8
7.4 Device Functional Modes ... 8
**8 Application and Implementation** ... 9
8.1 Application Information ... 9
8.2 Typical Application ... 9
8.3 Power Supply Recommendations ... 10
8.4 Layout ... 10
**9 Device and Documentation Support** ... 11
9.1 Documentation Support (Analog) ... 11
9.2 ドキュメントの更新通知を受け取る方法 ... 11
9.3 サポート・リソース ... 11
9.4 Trademarks ... 11
9.5 静電気放電に関する注意事項 ... 11
9.6 用語集 ... 11
**10 Revision History** ... 11
**11 Mechanical, Packaging, and Orderable Information** ... 12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# 4 Pin Configuration and Functions

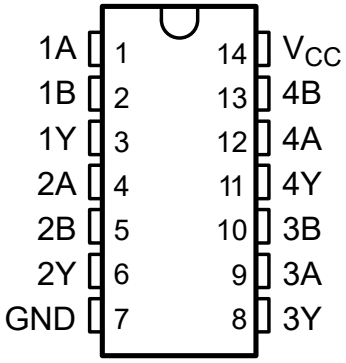


**図 4-1. D or PW Package, 14-Pin SOIC or TSSOP (Top View)**

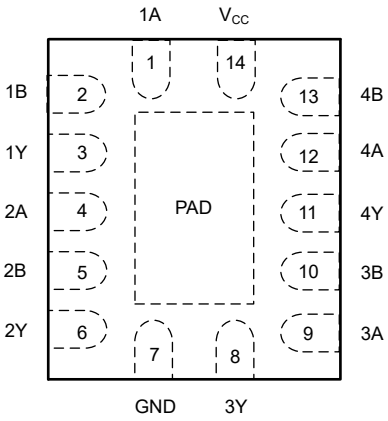


**図 4-2. BQA (Preview) Package, 14-Pin WQFN (Top View)**

**表 4-1. Pin Functions**

| PIN | | TYPE | DESCRIPTION |
|---|---|---|---|
| NAME | NO. | | |
| 1A | 1 | Input | Channel 1, Input A |
| 1B | 2 | Input | Channel 1, Input B |
| 1Y | 3 | Output | Channel 1, Output Y |
| 2A | 4 | Input | Channel 2, Input A |
| 2B | 5 | Input | Channel 2, Input B |
| 2Y | 6 | Output | Channel 2, Output Y |
| GND | 7 | — | Ground |
| 3Y | 8 | Output | Channel 3, Output Y |
| 3A | 9 | Input | Channel 3, Input A |
| 3B | 10 | Input | Channel 3, Input B |
| 4Y | 11 | Output | Channel 4, Output Y |
| 4A | 12 | Input | Channel 4, Input A |
| 4B | 13 | Input | Channel 4, Input B |
| $V_{CC}$ | 14 | — | Positive Supply |
| Thermal Pad(1) | | — | The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply |

(1) BQA package only.

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# 5 Specifications

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage range | | –0.5 | 7 | V |
| $V_I$ | Input voltage range(2) | | –0.5 | 7 | V |
| $V_O$ | Output voltage range(2) | | –0.5 | $V_{CC}$ + 0.5 | V |
| $I_{IK}$ | Input clamp current | $V_I$ < 0 | | –20 | mA |
| $I_{OK}$ | Output clamp current | $V_O$ < 0 or $V_O$ > $V_{CC}$ | | ±20 | mA |
| $I_O$ | Continuous output current | $V_O$ = 0 to $V_{CC}$ | | ±25 | mA |
| | Continuous current through $V_{CC}$ or GND | | | ±50 | mA |
| $T_{stg}$ | Storage temperature range | | –65 | 150 | °C |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 5.2 ESD Ratings

| | | | VALUE | UNIT |
|---|---|---|---|---|
| $V_{(ESD)}$ | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2(1) | ±2000 | V |
| | | Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B | ±1000 | |

(1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification

## 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| $V_{CC}$ | Supply voltage | 4.5 | 5.5 | V |
| $V_{IH}$ | High-level input voltage | 2 | | V |
| $V_{IL}$ | Low-level input voltage | | 0.8 | V |
| $V_I$ | Input voltage | 0 | 5.5 | V |
| $V_O$ | Output voltage | 0 | $V_{CC}$ | V |
| $I_{OH}$ | High-level output current | | –8 | mA |
| $I_{OL}$ | Low-level output current | | 8 | mA |
| Δt/Δv | Input transition rise or fall rate | | 20 | ns/V |
| $T_A$ | Operating free-air temperature | –40 | 125 | °C |

(1) All unused inputs of the device must be held at $V_{CC}$ or GND to ensure proper device operation. Refer to the TI Application Report, *Implications of Slow or Floating CMOS Inputs*

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## 5.4 Thermal Information

| THERMAL METRIC[1] | | SN74AHCT08Q-Q1 | | | UNIT |
|---|---|---|---|---|---|
| | | D (SOIC) | PW (TSSOP) | BQA (WQFN) | |
| | | 14 PINS | 14 PINS | 14 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 124.6 | 113 | 88.3 | °C/W |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics*

## 5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | $V_{CC}$ | $T_A$ = 25°C | | | -40°C to 125°C | | UNIT |
|---|---|---|---|---|---|---|---|---|
| | | | MIN | TYP | MAX | MIN | MAX | |
| $V_{OH}$ | $I_{OH}$ = –50 µA | 4.5 V | 4.4 | 4.5 | | 4.4 | | V |
| | $I_{OH}$ = –8 mA | | 3.94 | | | 3.8 | | |
| $V_{OL}$ | $I_{OL}$ = 50 µA | 4.5 V | | | 0.1 | | 0.1 | V |
| | $I_{OL}$ = 8 mA | | | | 0.36 | | 0.44 | |
| $I_I$ | $V_I$ = 5.5 V or GND | 0 V to 5.5 V | | | ±0.1 | | ±1 | µA |
| $I_{CC}$ | $V_I$ = $V_{CC}$ or GND, $I_O$ = 0 | 5.5 V | | | 2 | | 20 | µA |
| $\Delta I_{CC}$ [1] | One input at 3.4 V, Other inputs at $V_{CC}$ or GND | 5.5 V | | | 1.35 | | 1.5 | mA |
| $C_i$ | $V_I$ = $V_{CC}$ or GND | 5 V | | 4 | 10 | | 10 | pF |

(1) This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or $V_{CC}$.

## 5.6 Switching Characteristics, $V_{CC}$ = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see 図 6-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | LOAD CAPACITANCE | $T_A$ = 25°C | | | -40°C to 125°C | | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| | | | | MIN | TYP | MAX | MIN | MAX | |
| $t_{PLH}$ | A or B | Y | $C_L$ = 15 pF | | 5 | 6.9 | 1 | 8 | ns |
| $t_{PHL}$ | | | | | 5 | 6.9 | 1 | 8 | |
| $t_{PLH}$ | A or B | Y | $C_L$ = 50 pF | | 5.5 | 7.9 | 1 | 9 | ns |
| $t_{PHL}$ | | | | | 5.5 | 7.9 | 1 | 9 | |

## 5.7 Noise Characteristics

$V_{CC}$ = 5 V, $C_L$ = 50 pF, $T_A$ = 25°C[1]

| PARAMETER | | SN74AHCT08Q-Q1 | | | UNIT |
|---|---|---|---|---|---|
| | | MIN | TYP | MAX | |
| $V_{OL(P)}$ | Quiet output, maximum dynamic $V_{OL}$ | | 0.4 | 0.8 | V |
| $V_{OL(V)}$ | Quiet output, minimum dynamic $V_{OL}$ | | –0.4 | –0.8 | V |
| $V_{OH(V)}$ | Quiet output, minimum dynamic $V_{OH}$ | 4.4 | | | V |
| $V_{IH(D)}$ | High-level dynamic input voltage | 2 | | | V |
| $V_{IL(D)}$ | Low-level dynamic input voltage | | | 0.8 | V |

(1) Characteristics are for surface-mount packages only.

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## 5.8 Operating Characteristics

$V_{CC}$ = 5 V, $T_A$ = 25°C

| PARAMETER | | TEST CONDITIONS | | TYP | UNIT |
|---|---|---|---|---|---|
| $C_{pd}$ | Power dissipation capacitance | No load, | f = 1 MHz | 18 | pF |

## 5.9 Typical Characteristics

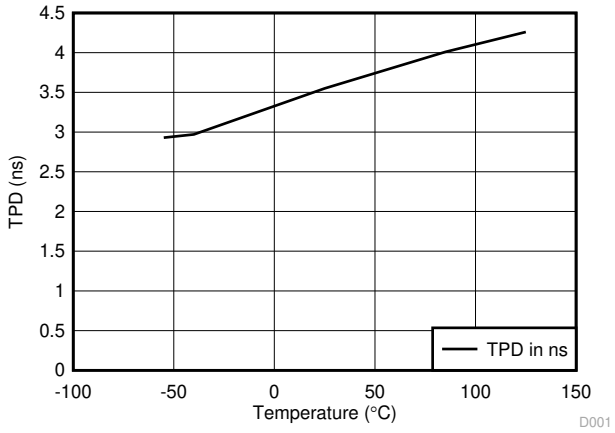


図 5-1. TPD vs Temperature


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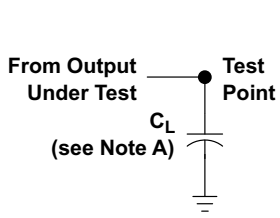
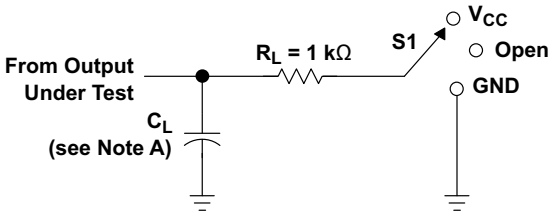
## 6 Parameter Measurement Information

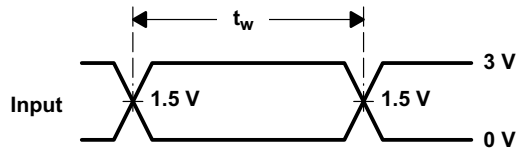



LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

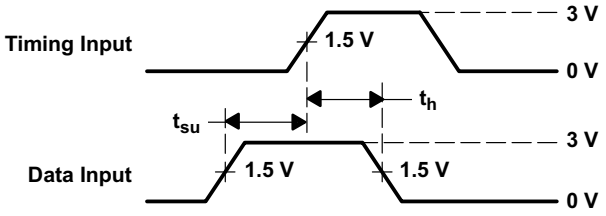



LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

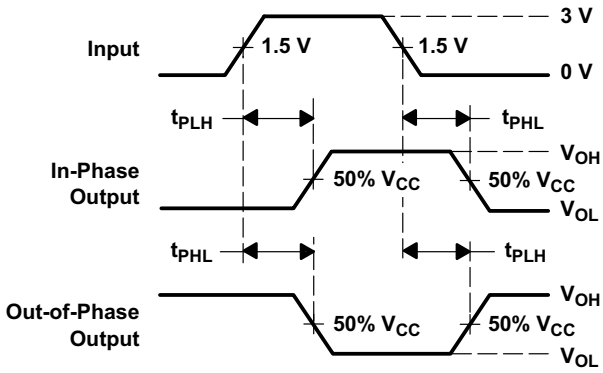
| TEST | S1 |
|---|---|
| $t_{PLH}/t_{PHL}$ | Open |
| $t_{PLZ}/t_{PZL}$ | $V_{CC}$ |
| $t_{PHZ}/t_{PZH}$ | GND |
| Open Drain | $V_{CC}$ |



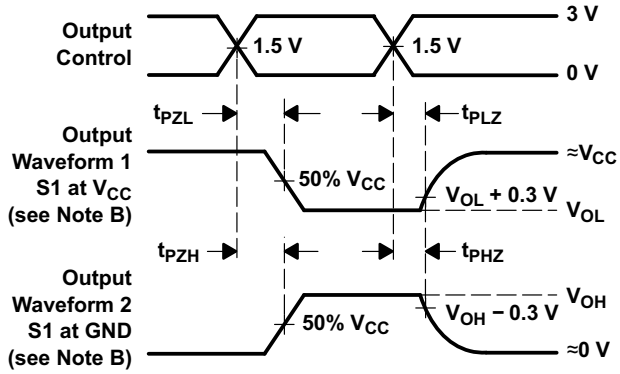

VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 3 ns, $t_f$ ≤ 3 ns.
D. The outputs are measured one at a time with one input transition per measurement.
E. All parameters and waveforms are not applicable to all devices.

**図 6-1. Load Circuit and Voltage Waveforms**

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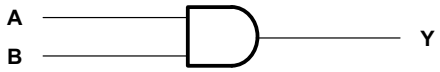
# 7 Detailed Description

## 7.1 Overview

The SN74AHCT08Q-Q1 devices are quadruple 2-input positive-AND gates with low drive that will produce slow rise and fall times. This slow transition reduces ringing on the output signal. The device has TTL inputs that allow up translation from 3.3 V to 5 V. The inputs are high impedance when $V_{CC}$ = 0 V.

## 7.2 Functional Block Diagram




## 7.3 Feature Description

- Slow rise and fall time on outputs allow for low-noise outputs
- TTL inputs allow up translation from 3.3 V to 5 V

## 7.4 Device Functional Modes

表 7-1 is the function table for the SN74AHCT08Q-Q1.

**表 7-1. Function Table (Each Gate)**

| INPUTS | | OUTPUT |
|---|---|---|
| A | B | Y |
| H | H | H |
| L | X | L |
| X | L | L |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# 8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 8.1 Application Information

The SN74AHCT08Q-Q1 devices are low-drive CMOS devices that can be used for a multitude of bus-interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The TTL inputs can except voltages down to 3.3 V and translate up to 5 V.

## 8.2 Typical Application

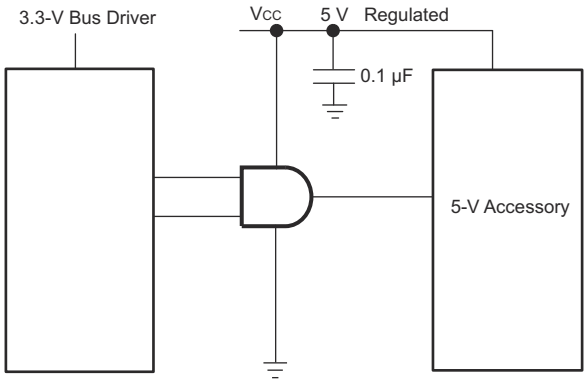


**図 8-1. Typical Application Diagram**

### 8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

### 8.2.2 Detailed Design Procedure

1. Recommended input conditions:
   - Rise time and fall time specs: See (Δt/ΔV) in the *Recommended Operating Conditions* table.
   - Specified High and low levels: See ($V_{IH}$ and $V_{IL}$) in the *Recommended Operating Conditions* table.
   - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid $V_{CC}$
2. Recommend output conditions:
   - Load currents should not exceed 25 mA per output and 50 mA total for the part
   - Outputs should not be pulled above $V_{CC}$

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### 8.2.3 Application Curves

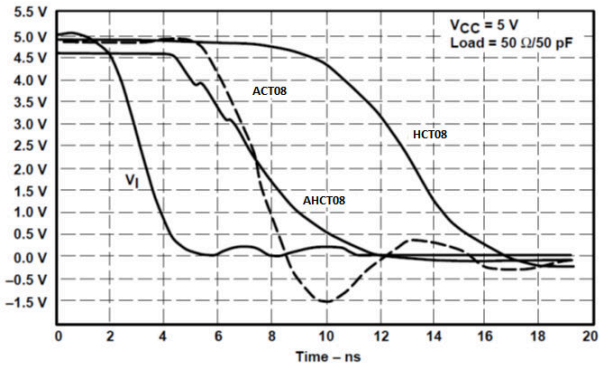


**図 8-2. Switching Characteristics Comparison**

## 8.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each $V_{CC}$ pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 µF is recommended. If there are multiple $V_{CC}$ pins, 0.01 µF or 0.022 µF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 µF and 1 µF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

## 8.4 Layout

### 8.4.1 Layout Guidelines

When using multiple bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. 図 8-3 shows the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or $V_{CC}$; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, then it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs, so they cannot float when disabled.

### 8.4.2 Layout Example

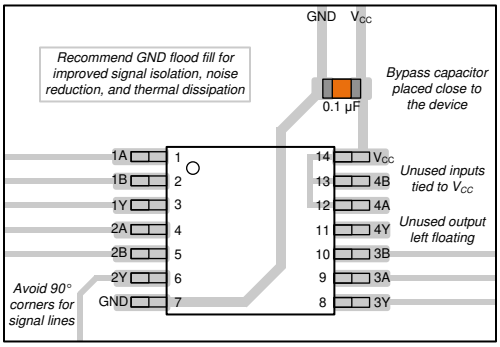


**図 8-3. Layout example for the SN74AHCT08Q-Q1**


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# 9 Device and Documentation Support

## 9.1 Documentation Support (Analog)

### 9.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**表 9-1. Related Links**

| PARTS | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|---|---|---|---|---|---|
| SN74AHCT08Q-Q1 | Click here | Click here | Click here | Click here | Click here |

## 9.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。 変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

## 9.6 用語集

テキサス・インスツルメンツ用語集　　この用語集には、用語や略語の一覧および定義が記載されています。

# 10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Changes from Revision C (May 2023) to Revision D (February 2024) | Page |
|---|---|
| • 「パッケージ情報」表にパッケージ サイズを追加 | 1 |
| • Updated RθJA value: D = 86 to 124.6, all values in °C/W | 5 |

| Changes from Revision B (December 2022) to Revision C (May 2023) | Page |
|---|---|
| • BQA パッケージのステータスをプレビューからアクティブに変更 | 1 |

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## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.


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## PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| SN74AHCT08QDRG4Q1 | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHCT08Q |
| SN74AHCT08QDRG4Q1.A | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHCT08Q |
| SN74AHCT08QDRQ1 | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHCT08Q |
| SN74AHCT08QDRQ1.A | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHCT08Q |
| SN74AHCT08QPWRG4Q1 | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HB08Q |
| SN74AHCT08QPWRG4Q1.A | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HB08Q |
| SN74AHCT08QPWRQ1 | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HB08Q |
| SN74AHCT08QPWRQ1.A | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HB08Q |
| SN74AHCT08QWBQARQ1 | Active | Production | WQFN (BQA) \| 14 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHT08Q |
| SN74AHCT08QWBQARQ1.A | Active | Production | WQFN (BQA) \| 14 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AHT08Q |

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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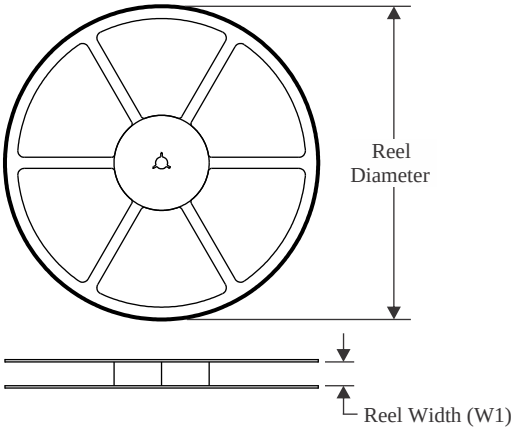
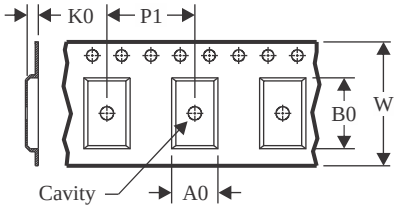
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

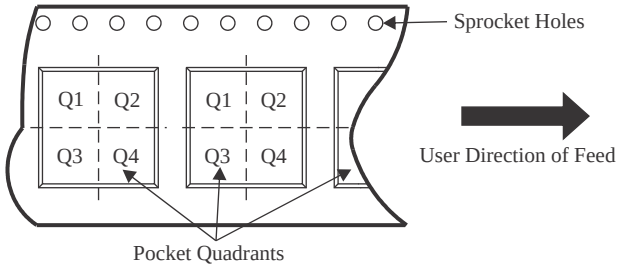



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

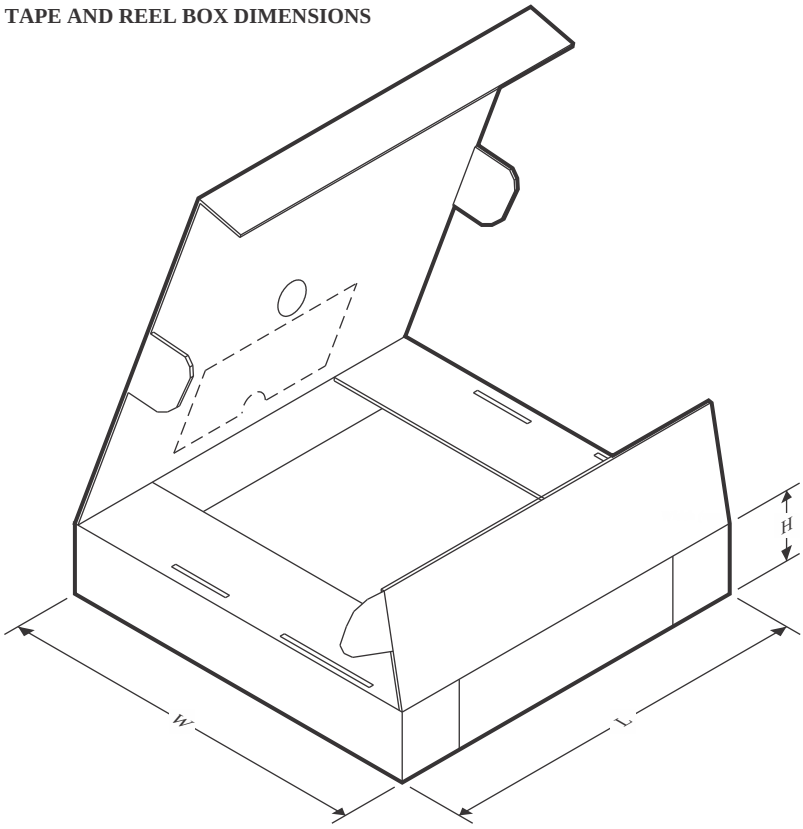
**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**




*All dimensions are nominal

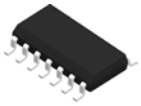
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| SN74AHCT08QDRG4Q1 | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| SN74AHCT08QDRQ1 | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| SN74AHCT08QPWRG4Q1 | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74AHCT08QPWRG4Q1 | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74AHCT08QPWRQ1 | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74AHCT08QWBQARQ1 | WQFN | BQA | 14 | 3000 | 180.0 | 12.4 | 2.8 | 3.3 | 1.1 | 4.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| SN74AHCT08QDRG4Q1 | SOIC | D | 14 | 2500 | 353.0 | 353.0 | 32.0 |
| SN74AHCT08QDRQ1 | SOIC | D | 14 | 2500 | 353.0 | 353.0 | 32.0 |
| SN74AHCT08QPWRG4Q1 | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| SN74AHCT08QPWRG4Q1 | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| SN74AHCT08QPWRQ1 | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| SN74AHCT08QWBQARQ1 | WQFN | BQA | 14 | 3000 | 210.0 | 185.0 | 35.0 |

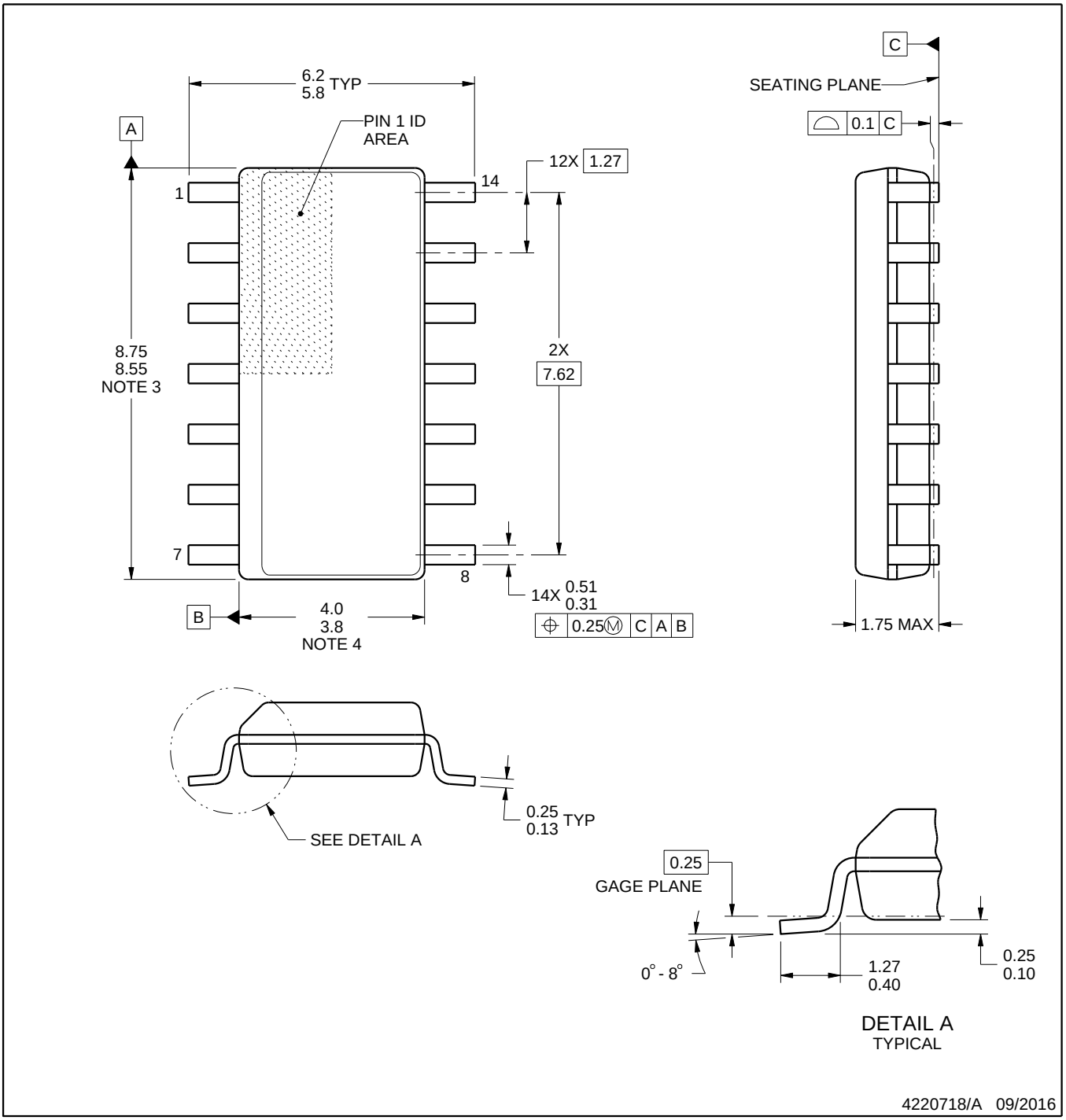


# PACKAGE OUTLINE

## D0014A

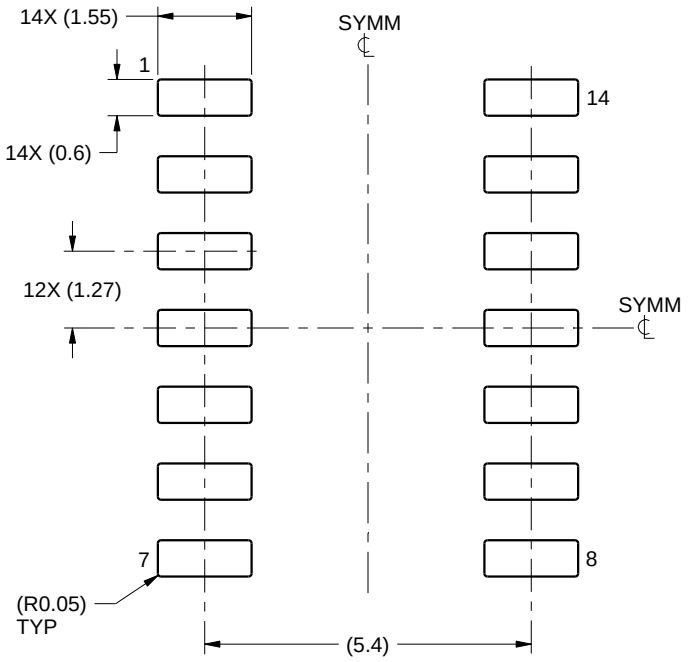
## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

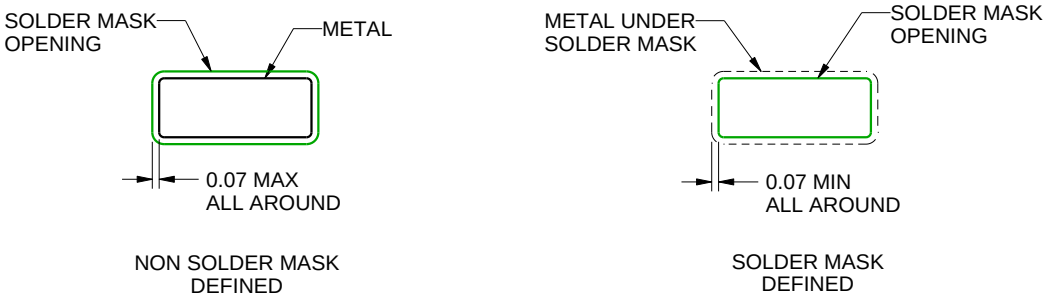



NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.




LAND PATTERN EXAMPLE
SCALE:8X




SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

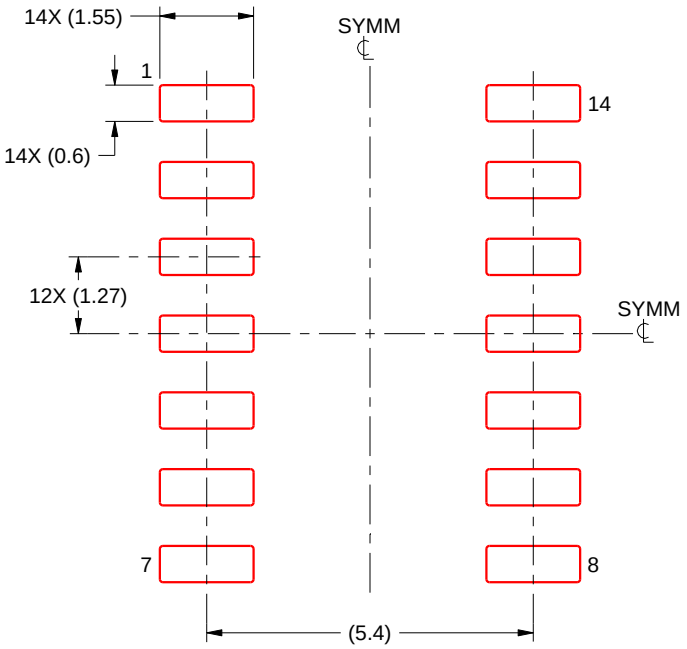
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

## D0014A

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

# GENERIC PACKAGE VIEW

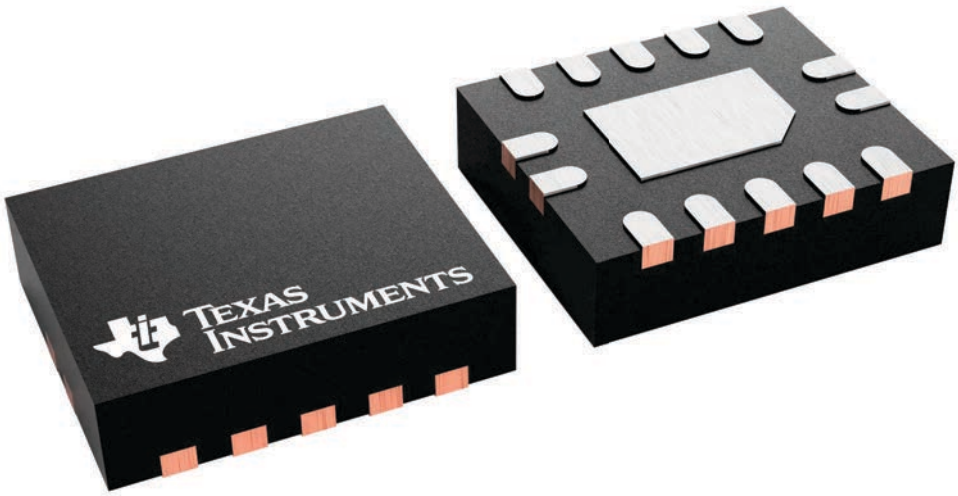
## BQA 14

## WQFN - 0.8 mm max height

**2.5 x 3, 0.5 mm pitch**

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



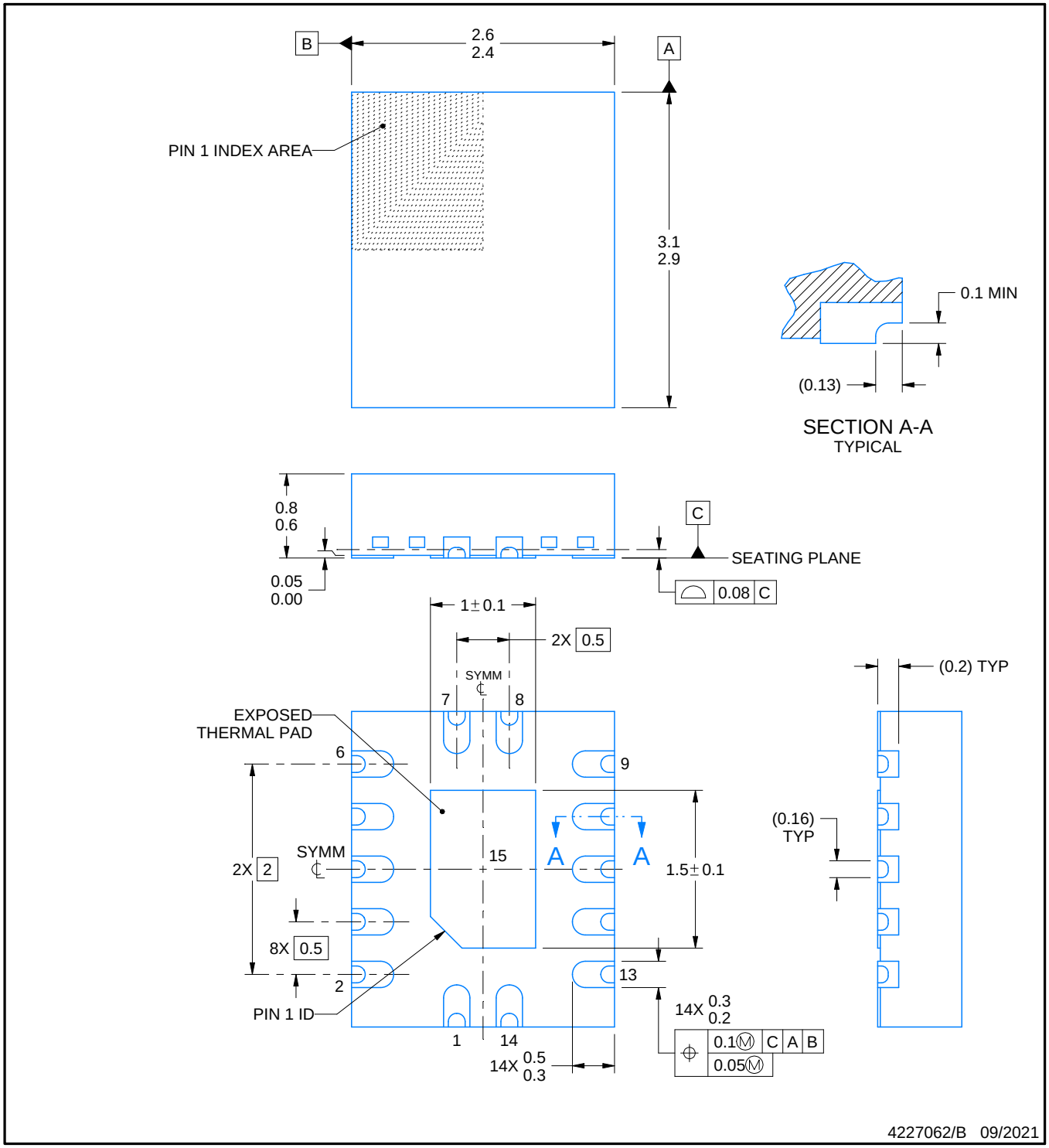

4227145/A

# BQA0014B

# PACKAGE OUTLINE

## WQFN - 0.8 mm max height

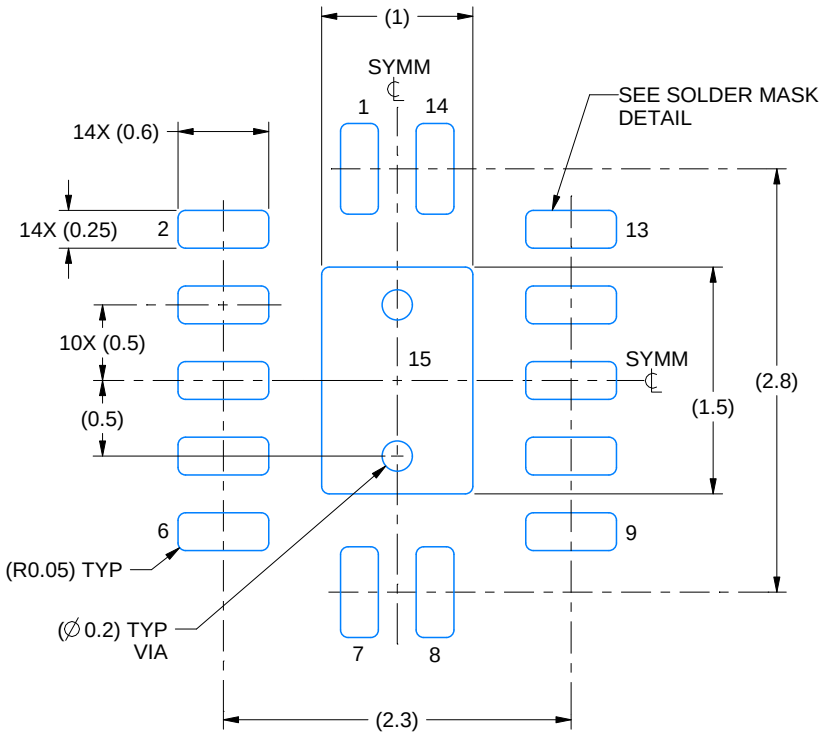
PLASTIC QUAD FLATPACK - NO LEAD



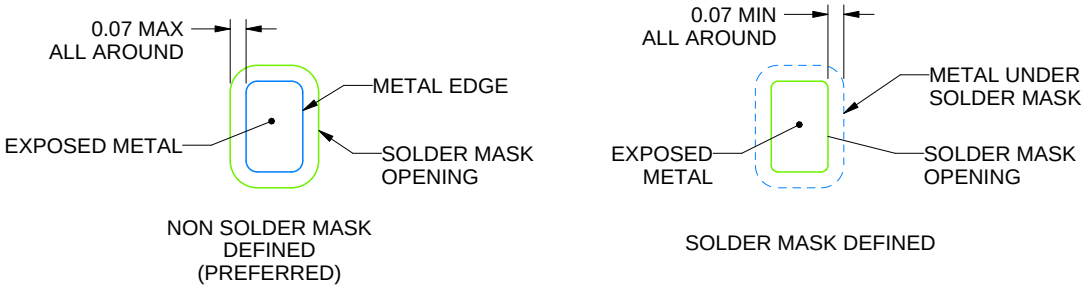

4227062/B 09/2021

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

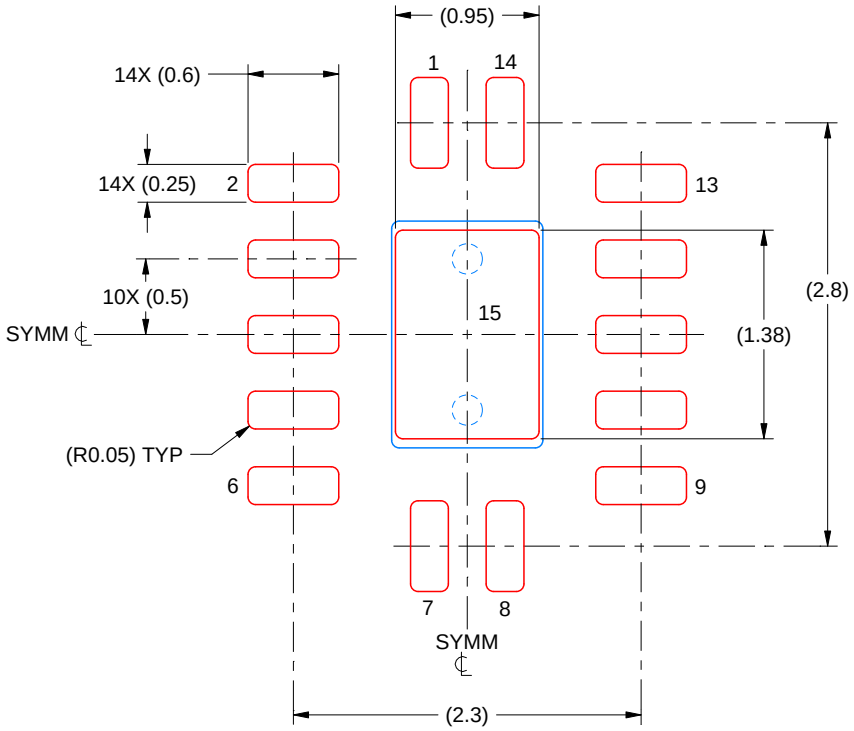



SOLDER MASK DETAILS

4227062/B 09/2021

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.




SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

EXPOSED PAD 15
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4227062/B 09/2021

NOTES: (continued)

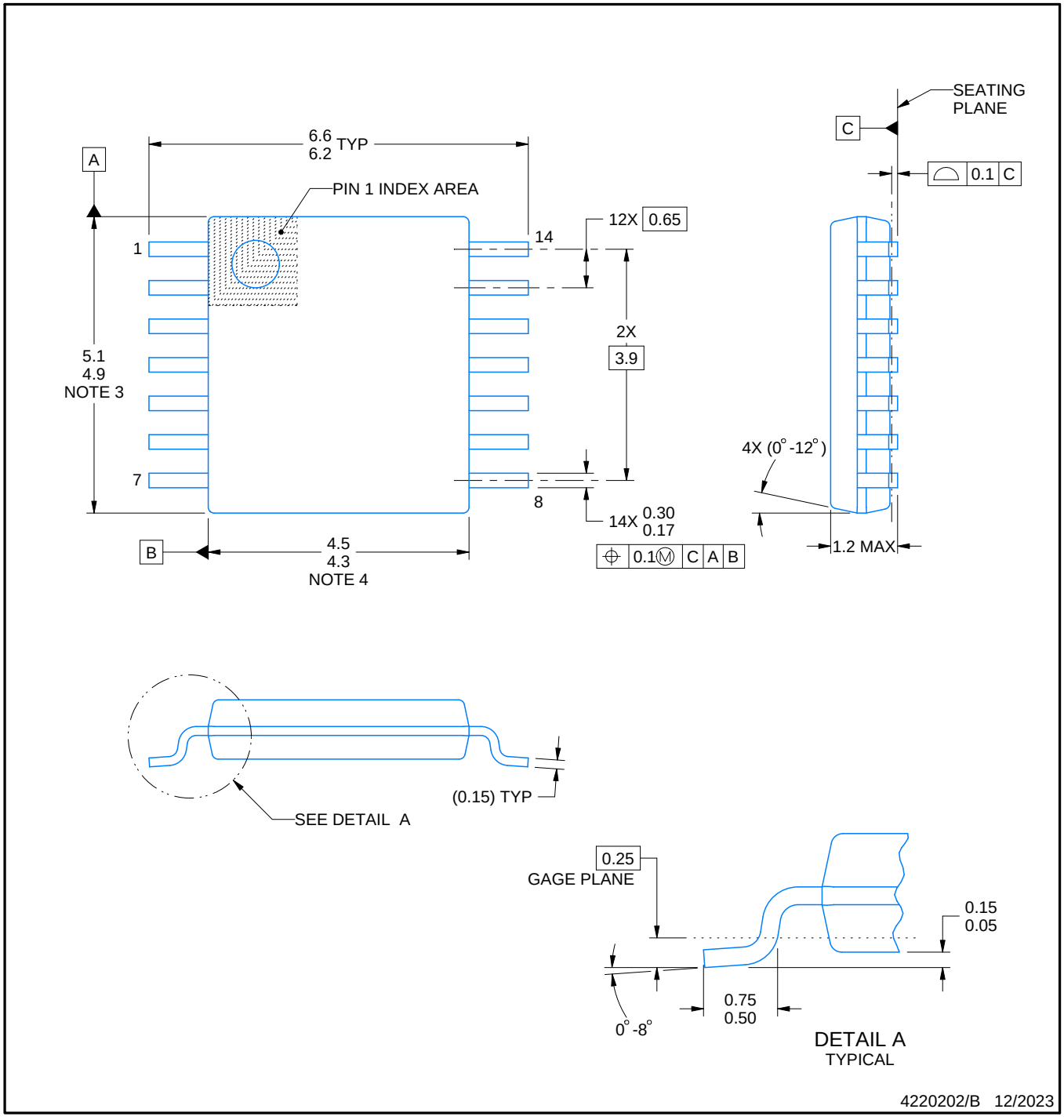
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

# PACKAGE OUTLINE

## PW0014A

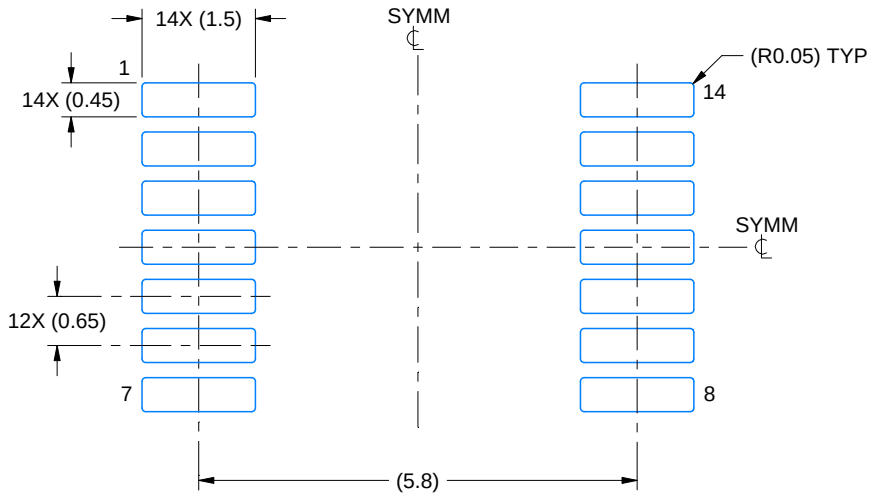
## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

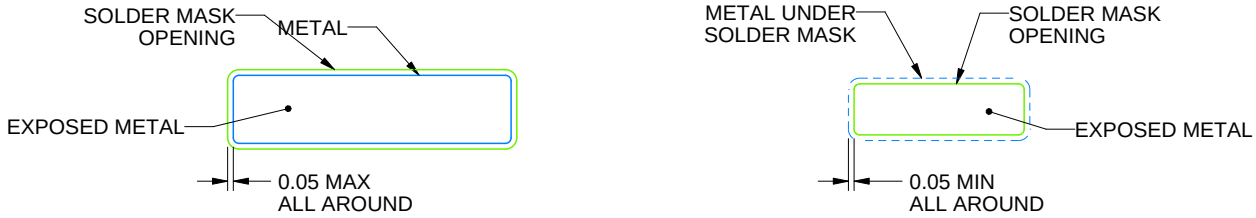



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

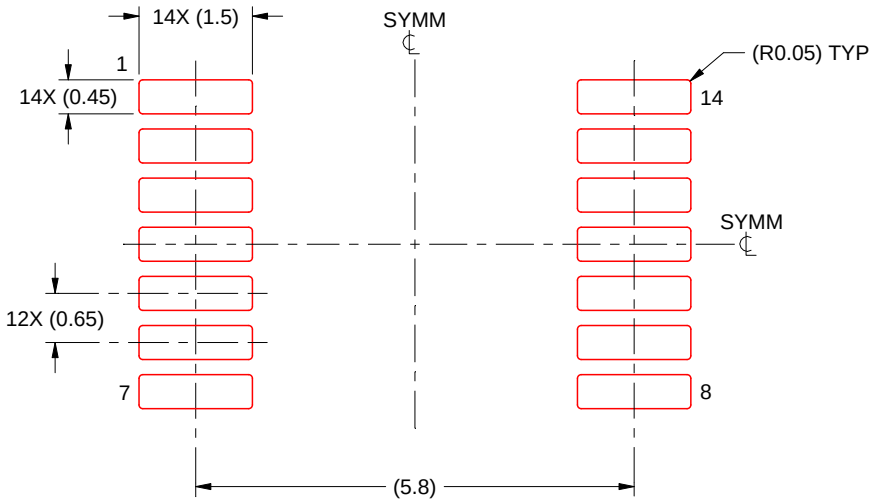



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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最終更新日：2025 年 10 月